



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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Features

- 60A Peak Avalanche Current
- $BV_{CBO} > 315V$
- $BV_{CEO} > 100V$
- Specifically Designed for Avalanche Mode Operation

Description

The NK-FMMT416 is a silicon planar bipolar transistor designed for operating in avalanche mode. Tight process control and low inductance packaging combine to produce high-current pulses with fast edges.

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (Approximate)

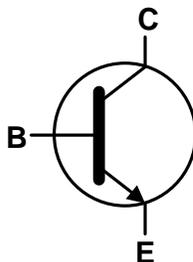
Applications

- Laser Diode Drivers for Ranging and Measurement (LIDAR)
- Radar Systems
- Fast Edge Switch Generator
- High-Speed Pulse Generators

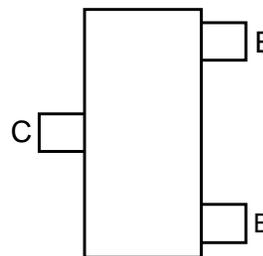
SOT23 (Type DN)



Top View



Device Symbol



Top View
Pin-Out

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	315	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	500	mA
Peak Collector Current (Pulse Width = 20ns)	I _{CM}	60	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

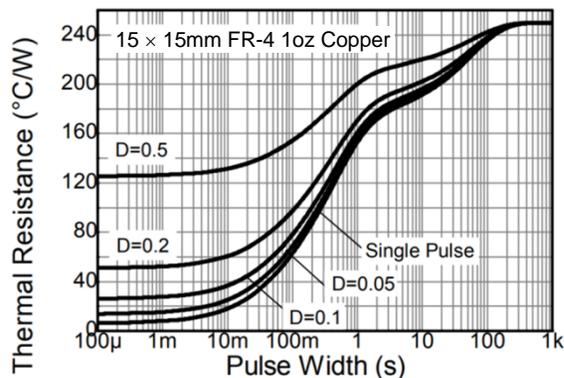
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	250	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	197	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 7)

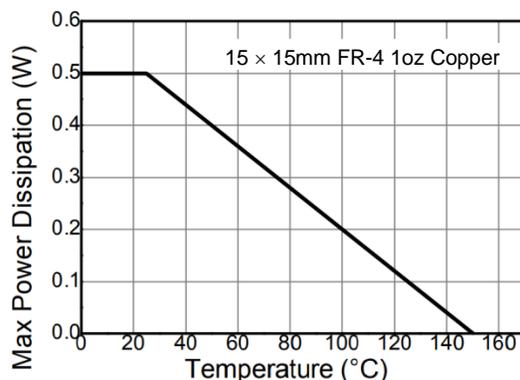
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 15mm × 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

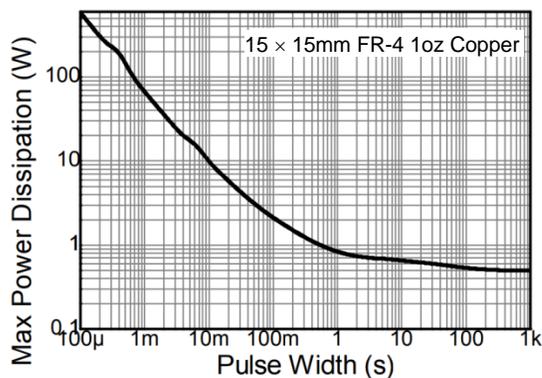
Thermal Characteristics and Derating information



Transient Thermal Impedance



Derating Curve



Pulse Power Dissipation

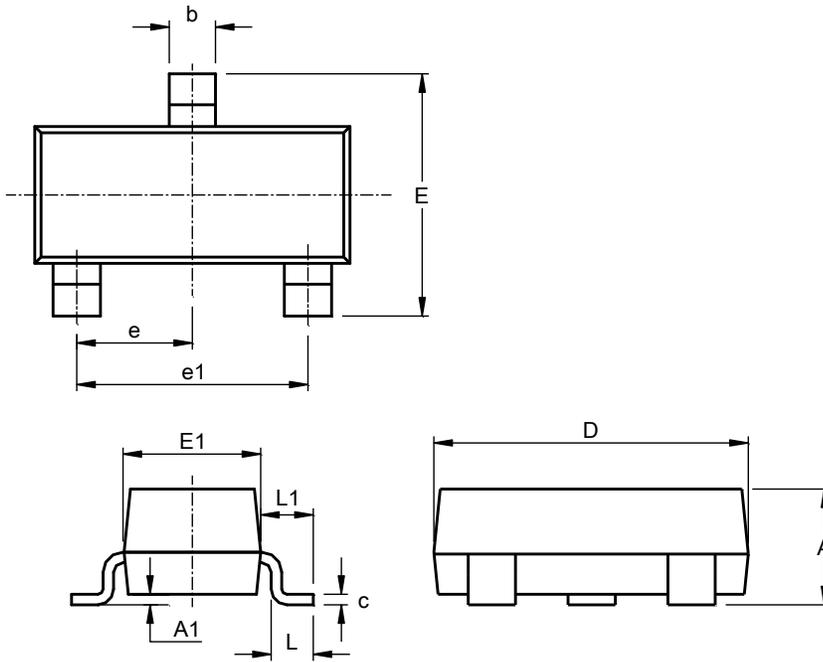
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	315	—	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	100	—	—	V	$I_C = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	100 10	nA μA	$V_{CB} = 310\text{V}$ $V_{CB} = 310\text{V}, T_J = +100^\circ\text{C}$
Emitter Cutoff Current	I_{EBO}	—	—	20	nA	$V_{EB} = 6\text{V}$
Static Forward Current Transfer Ratio (Note 8)	h_{FE}	100	—	—	—	$I_C = 10\text{mA}, V_{CE} = 10\text{V}$
Collector-Emitter Saturation Voltage (Note 8)	$V_{CE(sat)}$	—	—	100	mV	$I_C = 10\text{mA}, I_B = 1\text{mA}$
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(sat)}$	—	—	800	mV	$I_C = 10\text{mA}, I_B = 1\text{mA}$
Current in Second Breakdown (Pulsed)	I_{USB}	—	25 35	—	A A	$V_C = 200\text{V}, C_{CE} = 620\text{pF}$ $V_C = 250\text{V}, C_{CE} = 620\text{pF}$
Collector-Emitter Inductance	L_{ce}	—	2.5	—	nH	Standard SOT23 leads
Output Capacitance	C_{cbo}	—	—	8	pF	$V_{CB} = 20\text{V}, I_E = 0$ $f = 100\text{MHz}$
Transition Frequency	f_T	40	—	—	MHz	$V_{CE} = 20\text{V}, I_C = 10\text{mA},$ $f = 20\text{MHz}$

Note: 8. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Package Outline Dimensions

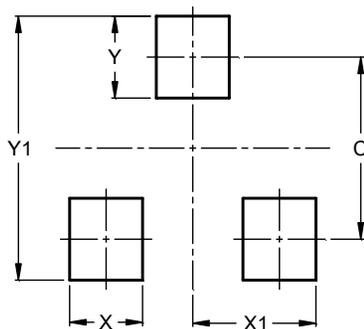
SOT23 (Type DN)



SOT23 Type DN			
Dim	Min	Max	Typ
A	0.89	1.12	1.00
A1	0.01	0.10	0.05
b	0.30	0.51	0.45
c	0.08	0.20	0.10
D	2.80	3.04	3.00
E	2.10	2.64	2.42
E1	1.20	1.40	1.37
e	0.95 REF		
e1	1.90 REF		
L	0.25	0.60	0.30
L1	0.45	0.62	0.54
All Dimensions in mm			

Suggested Pad Layout

SOT23 (Type DN)



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9